TDA7050 Low voltage mono/stereo power amplifier

INTEGRATED CIRCUITS

Product specification File under Integrated Circuits, IC01 June 1989

Philips Semiconductors





Low voltage mono/stereo power amplifier

TDA7050

GENERAL DESCRIPTION

The TDA7050 is a low voltage audio amplifier for small radios with headphones (such as watch, pen and pocket radios) in mono (bridge-tied load) or stereo applications.

Features

- \bullet Limited to battery supply application only (typ. 3 and 4 V)
- \bullet Operates with supply voltage down to 1,6 $\rm V$
- · No external components required
- Very low quiescent current
- · Fixed integrated gain of 26 dB, floating differential input
- Flexibility in use mono BTL as well as stereo
- Small dimension of encapsulation (see package design example)

QUICK REFERENCE DATA

Supply voltage range	VP	1,6	to 6,0 V
Total quiescent current (at $V_P = 3 V$)	Inot	typ.	3,2 mA
Bridge tied load application (BTL)			
Output power at R _L = 32 Ω			
$V_P = 3 \text{ V}; d_{tot} = 10\%$	Po	typ.	140 mW
D.C. output offset voltage between the outputs	$ \Delta V $	max.	70 mV
Noise output voltage (r.m.s. value)			
at $f = 1 \text{ kHz}$; $Rs = 5 \text{ k}\Omega$	Vno(rms)	typ.	140 µV
Stereo application			
Output power at R.1 = 32 Ω			
$d_{tot} = 10\%$; $V_P = 3 \text{ V}$	Po	typ.	35 mW
$d_{tot} = 10\%$; $Vv = 4.5 \text{ V}$	Po	typ.	75 mW
Channel separation at $Rs = 0 \Omega$; $f = 1 \text{ kHz}$	α	typ.	40 dB
Noise output voltage (r.m.s. value)			
at $f = 1 \text{ kHz}$; $Rs = 5 \text{ k}\Omega$	V _{no(rms)}	typ.	100 µV

PACKAGE OUTLINE

8-lead DIL; plastic (SOT97); SOT97-1; 1996 July 23.

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RATINGS						
Limiting values	in accordance	with the	Absolute	Maximum	System	(IEC 134)

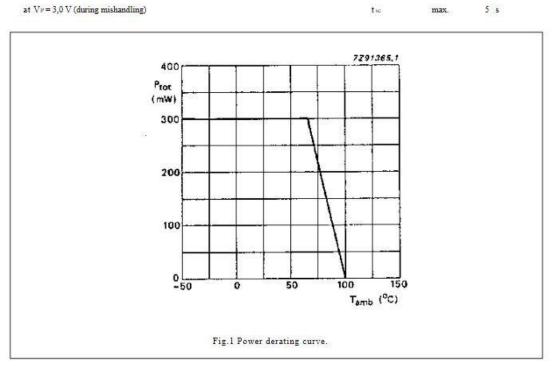
6 V Supply voltage V_{P} Peak output current max. 150 mA Total power dissipation see derating curve Fig.1 -55 to + 150 °C Storage temperature range Tstg 100 °C Crystal temperature max.

tsc

max.

A.C. and d.c. short-circuit duration

at $V_P = 3.0 \text{ V}$ (during mishandling)



THERMAL RESISTANCE

110 K/W From junction to ambient R_{thj-a} =

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CHARACTERISTICS

 $V_P = 3 \text{ V; } f = 1 \text{ kHz; } R_L = 32 \Omega; T_{\rm smb} = 25 \text{ °C; unless otherwise specified}$

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply					
Supply voltage	VP	1,6	*	6,0	v
Total quiescent current	Isca	-	3,2	4	mA
Bridge-tied load application (BTL); see Fig.4					
Output power; note 1					
$V_P = 3.0 \text{ V; } d_{tot} = 10\%$	Pn	-	140) - /3	mW
$V_P = 4.5 \text{ V}$; $d_{tot} = 10\% (R_L = 64 \Omega)P_{c}$	1.00	-	150	4	mW
Voltage gain	G	1237	32	226	dB
Noise output voltage (r.m.s. value)				2538	
$R_s = 5 \text{ k}\Omega; f = 1 \text{ kHz}$	Vno(ma)	-	140	- μ V	
$R_S = 0 \Omega$; $f = 500 \text{ kHz}$; $B = 5 \text{ kHz}$	Vno(ms)	-	tbf	- μ V	
D.C. output offset voltage (at $R_S = 5 \text{ k}\Omega) \Delta V $		-		70	mV
Input impedance (at RS=0) Zi 1			200		M^{Ω}
Input bias current	I.	678	40	5%	nA
Stereo application; see Fig.5					
Output power; note 1					
VP = 3,0 V; dot = 10%	Po	-	35	23	mW
$V_P = 4,5 \text{ V}; d_{tot} = 10\%$	\mathbf{p}_{α}	200	75	200	mW
Voltage gain	G.	24.5	26	27.5	dB
Noise output voltage (r.m.s. value)					
$Rs = 5 k\Omega$; $f = 1 kHz$	Vno(ms)	-	100	- μ V	
$Rs = 0 \Omega$; $f = 500 \text{ kHz}$; $B = 5 \text{ kHz}$	Vno(ms)	1200	tbf	- μ V	
Channel separation					
$R_S = 0 \Omega_c^c f = 1 \text{ kHz}$	a.	30	40	(2 5	dB
Input impedance (at RS = 00) Zi 2		10.000	-8		M^{Ω}
Input bias current	I.	-	20	40	nA

Note

Output power is measured directly at the output pins of the IC. It is shown as a function of the supply voltage in Fig.2 (BTL application) and Fig.3 (stereo application).

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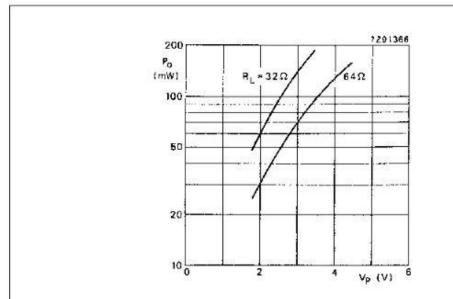


Fig.2 Output power across the load impedance (R.) as a function of supply voltage (VP) in BTL application. Measurements were made at f=1~kHz; $d_{tot}=10\%$; $T_{anth}=25~^{\circ}C$.

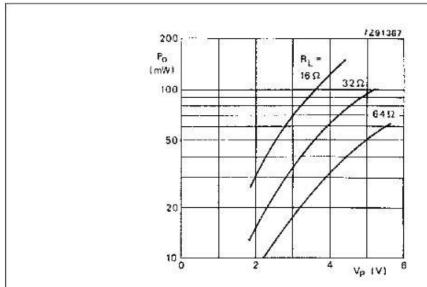
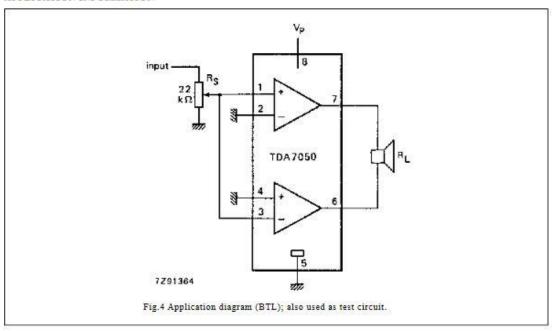


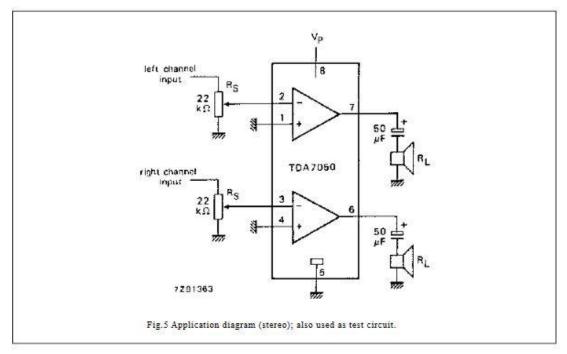
Fig.3 Output power across the load impedance (Ri) as a function of supply voltage (VP) in stereo application. Measurements were made at f=1 kHz; $d_{tot}=10\%$; $T_{amb}=25$ °C.

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APPLICATION INFORMATION





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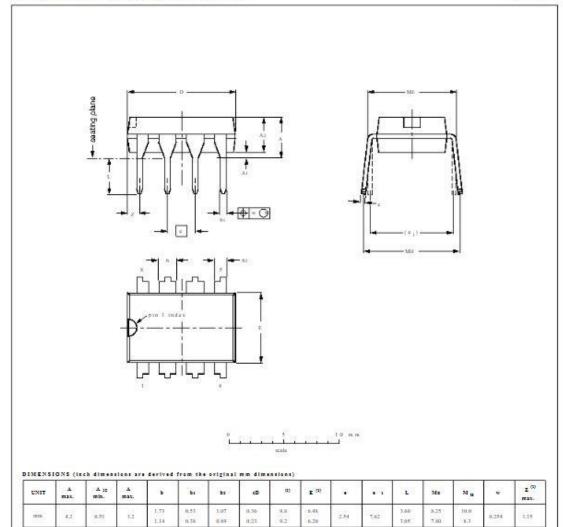
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PACKAGE OUTLINE

DIPS: plastic dual in-line package; 8 leads (300 mil)

SOT97-1

0.045



Note

0.17

1. Plastic or metal protructions of 0.25 mm maximum per side are not included.

0.021

0.047

0.014

OUTLINE VERSION		REFERE	NCES	EUROPEAN	
	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
50197-1	050001	MO-001AN		€ •	92-11-17 95-02-04

0.19

0.14

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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "IC Package Databook" (order code 9398 652 90011).

Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature (Todg max). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

Repairing soldered joints

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

DEFINITIONS

This data sheet contains target or goal specifications for product development.	
This data sheet contains preliminary data; supplementary data may be published later.	
This data sheet contains final product specifications.	
accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation my other conditions above those given in the Characteristics sections of the specification imiting values for extended periods may affect device reliability.	
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LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Where application information is given, it is advisory and does not form part of the specification.